TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SP97TU, TC7SP98TU

Low Voltage Single Configurable Multiple Function Gate with 3.6 V Tolerant Inputs and Outputs

The TC7SP97,98 is a high performance CMOS multiple Function Gate which is guaranteed to operate from 1.2-V to 3.6-V. Designed for use in 1.5 V, 1.8 V, 2.5 V or 3.3 V systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

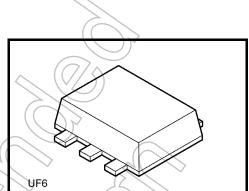
It is also designed with over voltage tolerant inputs and outputs up to  $3.6\ V$ .

It independently consists of three circuits for Multiple Function Gate.

The output state is determined by seven patterns of 3-inputs.

The user can choose the functions of Multiplexer, AND, OR NAND, Schmitt Inverter, and Schmitt Buffer.

All inputs are equipped with protection circuits against static discharge.



Weight: 0.007 g(typ)

#### **Features**

• Low-voltage operation  $V_{CC} = 1.2 \text{ to } 3.6 \text{ V}$ 

• High-speed operation :  $t_{pd} = 8.5 \text{ ns (max)} (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$ 

 $t_{pd} = 12.0 \text{ ns (max) (VCC} = 2.3 \text{ to } 2.7 \text{ V)}$ 

• Output current :  $|I_{OH}|/I_{OL} = \pm 8 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$ 

 $I_{OH} / I_{OL} = \pm 4 \text{ mA (min)} (V_{CC} = 2.3 \text{ V})$ 

 $I_{OH} I I_{OL} = \pm 1.5 \text{ mA (min)} (V_{CC} = 1.65 \text{ V})$ 

• Latch-up performance : -300 mA

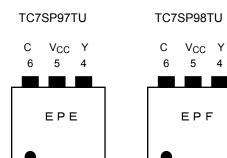
• ESD performance : Machine model  $\geq \pm 200 \text{ V}$ 

Human body model ≥ ±2000 V

Package : UF6

· Power-down protection is provided on all inputs and outputs

### Pin Assignment (top view)



#### **Truth Table**

B GND A

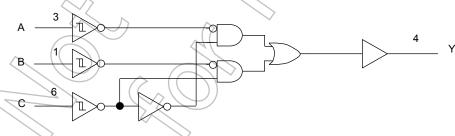
INPUTS			OUTPUT			
	INFOIS		TC7SP97	TC7SP98		
Α	В	С	Y	Y		
L	L	L	L	Н		
L	L	Н	L	Н		
L	Н	L	Н	L ((		
L	Н	Н	L	H		
Н	L	L	L	(H \		
Н	L	Н	Н			
Н	Н	L	H (	(/\f\)		
Н	Н	Н	H			

GND A

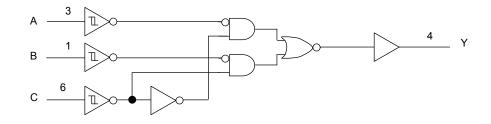
В

## **System Diagram**





TC7SP98



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# Logic configrations(1/2)

Function	Input Condition	TC7SP97 Logic symbol	TC7SP98 Logic symbol	FUNCTION TABLE
SP97 AND SP98 NAND	A=INPUT B=L-Level C=INPUT Y=OUTPUT	A Y	A Y	A B C Y 98 D D D D D D D D D D D D D D D D D D
SP97 OR	A=H-Level B=INPUT	В — У	B V	A B C Y 97 98
SP98 NOR	C=INPUT Y=OUTPUT	C Tr	cY	H L L L H H H L H L
SP97 Schmitt INV+NOR or Schmitt INV+AND SP98 Schmitt INV+OR or Schmitt INV+NAND	A=L-Level B=INPUT C=INPUT Y=OUTPUT	B OR OR C OF	B OR Y C OF OY	A B C 97 98 L L L L H L L H L H L H L H L
SP97 Schmitt INV+NAND or Schmitt INV+OR SP98 Schmitt INV+AND or Schmitt INV+AND	A=INPUT B=H-Level C=INPUT Y=OUTPUT	A OF Y C OF Y C OF	OR Y	A B C 97 98 L H L H L L H H L H H H H L H H H H L
SP97 2 to 1 Selector  SP98 2 to 1 Selector+INV	A=INPUT B=INPUT C=Select Y=OUTPUT	C A B Y	C A B Y	A B C Y 97 98 L L L L L H L H L H L H L L H L H L H L

# Logic configrations(2/2)

Function	Input	TC7SP97	TC7SP98	FUNCTION
0000	Condition	Logic symbol	Logic symbol	TABLE
SP97 Schmitt INV SP98 Schmitt Buffer	A=L-Level B=H-Level C=INPUT Y=OUTPUT	C Y	C Y	A B C Y 97 98 L H L H L L H
SP97				
Schmitt Buffer SP98 Schmitt INV	A=H-Level B=L-Level C=INPUT Y=OUTPUT	C Y	C P	A B C 97 98 H L L L H H L H H L
SP97 Schmitt Buffer	A=L-Level B=INPUT	В — 7	B T O Y	A B C 97 98
SP98 Schmitt INV	C=L-Level Y=OUTPUT	B Y	B	
SP97				
Schmitt Buffer	A=H-Level B=INPUT	В — У	B Y	A B C Y 97 98
SP98 Schmitt INV	C=L-Level Y=OUTPUT			H L L L H
SP97			V // //	
Schmitt Buffer	A=INPUT B=L-Level	A T	AY	A B C Y 97 98
SP98 Schmitt INV	C=H-Level Y=OUTPUT			L L H L H H L H H L

#### **Absolute Maximum Rating (Note1)**

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V <sub>CC</sub>	-0.5 to 4.6	V	
DC input voltage	V <sub>IN</sub>	-0.5 to 4.6	V	
		-0.5 to 4.6 (Note2)	4	
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5 (Note3)	V	
Input diode current	I <sub>IK</sub>	-20	mA	
Output diode current	lok	±20 (Note4)	mA (/	
DC output current	lout	±25	mA	
Power dissipation	PD	180	mW	
DC V <sub>CC</sub> /ground current	I <sub>CC</sub> /I <sub>GND</sub>	±25	mA	
Storage temperature	T <sub>stg</sub>	-65 to 150	ŝ	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction. Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2:  $V_{CC} = 0 V$ 

Note 3: High or Low state. I<sub>OUT</sub> absolute ratiingmust be observed.

Note 4:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$ 

## **Operating Range (Note1)**

Characteristics	Symbol	Rating	Unit	
Supply voltage	Vcc	1.2 to 3.6	V	
Input voltage	V <sub>IN</sub>	-0.3 to 3.6	٧	
Output voltage	Voit	0 to 3.6 (Note2)	V	
Output voltage	Vout	0 to V <sub>CC</sub> (Note3)	V	
		±8.0 (Note4)		
Output current	I <sub>OH</sub> /I <sub>OL</sub>	±4.0 (Note5)	mA	
		±1.5 (Note6)		
Operating temperature	Topt	-40 to 85	°C	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V<sub>CC</sub> or GND.

Note 2:  $V_{CC} = 0 \text{ V}$ 

Note 3: High or low state

Note 4:  $V_{CC} = 3.0$  to 3.6 V

Note 5:  $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$ 

Note 6:  $V_{CC} = 1.65 \text{ to } 1.8 \text{ V}$ 



#### **Electrical Characteristics**

### DC Characteristics ( $Ta = -40 \text{ to } 85^{\circ}\text{C}$ )

Characteris	tics	Symbol	Test Co	ndition	V 00	Min	Max	Unit
					V <sub>CC</sub> (V)		1.10	
					1.4		1.10	
					1.65		1.35	
	H-level	V <sub>P</sub>	_	-	2.3	( ) Y	1.70	V
				_	3.0		2.00	
					3.6	))	2.20	
Input voltage					1.2	0.10	2.20	
					1.4	0.10		
				$\mathcal{A}$	1.65	0.30		
	L-level	V <sub>N</sub>	_	-	2.3	0.50		V
				(7/6)	~	0.70		
					3.0	0.80	)	
					1.2	0.80	0.9	
			~		1.4	0.2	0.9	
					1.65	0.2	0.95	
Hysteresis voltage		V <sub>H</sub>		$\searrow$	2,3	0.2	1.0	V
			4	>	3.0	0.3	1.2	
					3.6	0.3	1.2	=
				I <sub>OH</sub> = -100 μA	1.2 to 1.3	V <sub>CC</sub> - 0.1	-	
		,		Ι <sub>ΟΗ</sub> = –500 μΑ	1.4 to 1.6	V <sub>CC</sub> - 0.2	_	
	H-level	V <sub>OH</sub> (	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -1.5 mA	1.65 to 1.95	V <sub>CC</sub> - 0.3	_	
			ALC THE	1 <sub>OH</sub> = -4.0 mA	2.3 to 2.7	V <sub>CC</sub> - 0.4	_	
			)	$I_{OH} = -8.0 \text{ mA}$	3.0 to 3.6	2.40	_	
Output voltage			\ \ (\( \)	I <sub>OL</sub> = 100 μA	1.2 to 1.3	_	0.10	V
				l <sub>OL</sub> = 500 μA	1.4 to 1.6	_	0.20	1
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 3.0 mA	1.65 to 1.95	_	0.25	
^	$\nearrow$			I <sub>OL</sub> = 4.0 mA	2.3 to 2.7	_	0.40	1
$\geq$	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\		$\sim$	I <sub>OL</sub> = 8.0 mA	3.0 to 3.6	_	0.40	
Input leakage current I <sub>IN</sub>		V <sub>IN</sub> = 0 to 3.6 V	1	1.2 to 3.6	_	±1.5	μА	
Power-off leakage current I <sub>OFF</sub>		V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6	5 V	0	_	1.5	μА	
		> ((	V <sub>IN</sub> = V <sub>CC</sub> or GND		1.2 to 3.6	_	3.0	
Quiescent supply current		/lcc	V <sub>CC</sub> ≤ V <sub>IN</sub> ≤ 3.6 V		1.2 to 3.6	_	±3.0	μА
Increase in I <sub>CC</sub> per in	nput	Δlcc	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V		2.7 to 3.6	_	100	1

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#### AC Characteristics (Ta = -40 to $85^{\circ}$ C, Input: $t_r = t_f = 3.0$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
	4	Figure 4 Figure 2	1.8± 0.15	1.0	21.0	
	t <sub>pLH</sub> t <sub>pHL</sub>	Figure 1, Figure 2 $CL = 10pF, R_L = 1M \Omega$	2.5 ± 0.2	0.8	10.0	ns
			3.3 ± 0.3	0.6	7.0	
Propagation delay time (A, B,C-Y)	t <sub>pLH</sub>	Figure 1, Figure 2 $CL = 15pF, R_L = 1M \Omega$	1.8± 0.15	1.0	23.0	
			2.5 ± 0.2	0.8	11.0	ns
			3.3 ± 0.3	0.6	7.7	
	t <sub>pLH</sub>	Figure 4 Figure 2	1.8± 0.15	1.0	27.0	
		Figure 1, Figure 2 $CL = 30pF$ , $R_L = 1M \Omega$	$2.5\pm0.2$	0.8	12.0	ns
		OL - 30pi (1/L - 11vi 52	$3.3 \pm 0.3$	0.6	8.5	

### Dynamic Switching Characteristics (Ta = 25°C, Input: $t_r = t_f = 3.0$ ns, $C_L = 30$ pF)

Characteristics	Symbol	Test Condition		Vcc (V)	Тур.	Unit
		V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V	(Note)	1.8	0.25	
Quiet output maximum dynamic $V_{\mbox{OL}}$	V <sub>OLP</sub>	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	2.5	0.6	V
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	(Note)	3.3	8.0	
	V <sub>OLV</sub>	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V	(Note)	1.8	-0.25	
Quiet output minimum dynamic $V_{\mbox{OL}}$		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V	(Note)	2.5	-0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	3.3	-0.8	
		V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V	(Note)	1.8	1.5	
Quiet output minimum dynamic $V_{\mbox{OH}}$	Vohv	VIH = 2.5 V, VIL = 0 V	(Note)	2.5	1.9	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	3.3	2.2	

Note: Parameter guaranteed by design.

#### Capacitive Characteristics (Ta = 25°C)

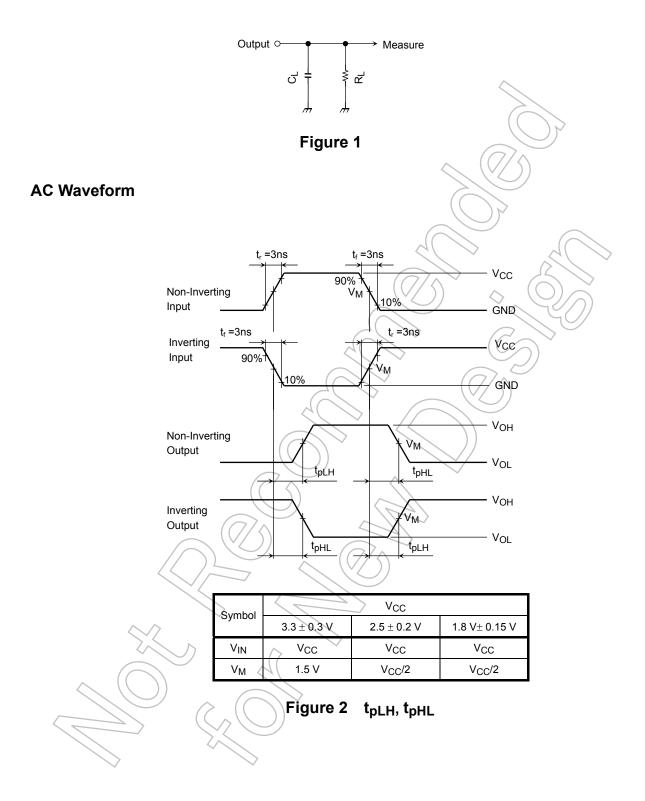
Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Тур.	Unit
Input capacitance	C <sub>IN</sub>	_		1.8, 2.5, 3.3	6	pF
Power dissipation capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz	(Note)	1.8, 2.5, 3.3	30	pF

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

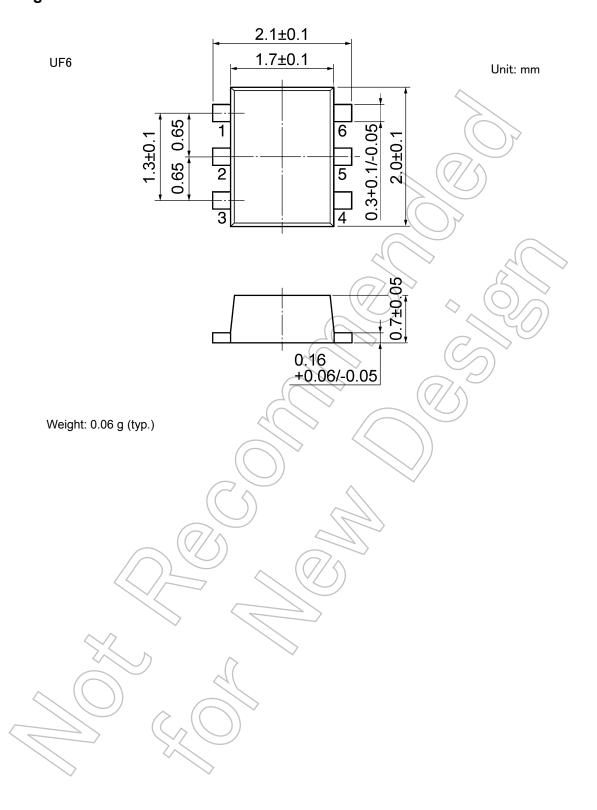
ICC (opr) = CPD · VCC · fIN + ICC

#### **AC Test Circuit**



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### **Package Dimensions**



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